





TPS2060, TPS2064 TPS2068, TPS2069

SLVS553K -MARCH 2005-REVISED MAY 2011

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# **CURRENT-LIMITED, POWER-DISTRIBUTION SWITCHES**

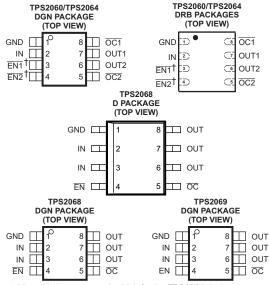
Check for Samples: TPS2060, TPS2064, TPS2068, TPS2069

#### **FEATURES**

- 70-mΩ High-Side MOSFET
- 1.5-A Continuous Current
- · Thermal and Short-Circuit Protection
- Accurate Current Limit (1.6 A min, 2.6 A max)
- Operating Range: 2.7 V to 5.5 V
- 0.6-ms Typical Rise Time
- · Undervoltage Lockout
- Deglitched Fault Report (OC)
- No OC Glitch During Power Up
- 1-µA Maximum Standby Supply Current
- · Reverse Current Blocking
- TPS2060/64 Temperature Range: 0°C to 70°C
- TPS2068/69 DGN Package Temperature Range: -40°C to 85°C
- TPS2068 D Package Temperature Range: 0°C to 70°C
- UL Listed File No. E169910
- TPS2068/69: CB Certified

## **APPLICATIONS**

- Heavy Capacitive Loads
- Short-Circuit Protections

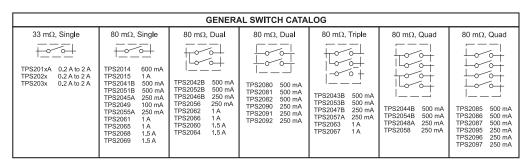


† All enable inputs are active high for the TPS2064 devices.

#### DESCRIPTION

The TPS206x power-distribution switches are intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. This device incorporates  $70\text{-m}\Omega$  N-channel MOSFET power switches for power-distribution systems that require single or dual power switches in a single package. Each switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent ( $\overline{OCx}$ ) logic output low. When continuous heavy overloads and short-circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures that the switch remains off until valid input voltage is present. Current limit is typically 2.1 A.



₩.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **AVAILABLE OPTION AND ORDERING INFORMATION**

TA	ENABLE	RECOMMENDED MAXIMUM	TYPICAL SHORT-CIRCUIT	NUMBER OF	PACKAGED DEVICES (1) (2)		
- 7		CONTINUOUS LOAD CURRENT	CURRENT LIMIT AT 25°C	SWITCHES	MSOP (DGN)	SON (DRB)	
0°C to 70°C	Active low			Duel	TPS2060DGN	TPS2060DRB	
0 0 10 70 0	Active high	1.5 A	2.1 A	Dual	TPS2064DGN	TPS2064DRB	
–40°C to 85°C	Active low			Cinalo	TPS2068DGN		
-40 C to 65 C	Active high			Single	TPS2069DGN		
0°C to 70°C	Active low			Single	TPS2068D	_	

- (1) The package is available taped and reeled. Add an R suffix to device types (e.g., TPS2060DGN).
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

## **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted(1)

			UNIT		
	Input voltage range, V <sub>I(IN)</sub>		–0.3 V to 6 V		
$V_{I}$	Input voltage range, V <sub>I(/ENx)</sub> , V <sub>I(ENx)</sub>		–0.3 V to 6 V		
	Voltage range, V <sub>I(/OC)</sub> , V <sub>I(/OCx)</sub>		–0.3 V to 6 V		
Vo	Output voltage range, V <sub>O(OUT)</sub> , V <sub>O(OUTx)</sub>		–0.3 V to 6 V		
Io	Continuous output current, I <sub>O(OUT)</sub> , I <sub>O(OUT)</sub>	<)	Internally limited		
	Continuous total power dissipation		See Dissipation Rating Table		
		TPS2060/64	0°C to 105°C		
$T_J$	Operating virtual junction temperature range	TPS2068/69 (DGN Package)	-40°C to 105°C		
	rango	TPS2068 (D Package)	0°C to 105°C		
T <sub>stg</sub>	Storage temperature range		–65°C to 150°C		
CCD	Flootroctatic discharge protection	Human body model MIL-STD-883C	2 kV		
ESD	Electrostatic discharge protection	Charge device model (CDM)	500 V		

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### DISSIPATING RATING TABLE(1)

PACKAGE	THERMAL RESISTANCE θ <sub>JA</sub>	T <sub>A</sub> < 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
DGN-8 <sup>(2)</sup>		1370 mW	17 mW/°C	600 mW	342 mW
D-8		585.82 mW	5.8582 mW/°C	322.20 mW	234.32 mW
DRB-8 (Low-K) <sup>(3)</sup>	270 °CW	370 mW	3.71 mW/°C	203 mW	148 mW
DRB-8 (High-K) <sup>(4)</sup>	60 °CW	1600 mW	16.67 mW/°C	916 mW	866 mW

- (1) Heatsink the PowerPad™per the recommendations of SLMA002. PCB used for recommendations per appendix A4.
- (2) See Recommended Operating Conditions Table for PowerPad connection guidelines to meet qualifying conditions for CB Certificate.
- (3) Soldered PowerPAD on a standard 2-layer PCB without vias for thermal pad. See TI application note SLMA002 for further details.
- 4) Soldered PowerPAD on a standard 4-layer PCB with vias for thermal pad. See TI application note SLMA002 for further details.



# **RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>**

			MIN	MAX	UNIT
V	Input voltage, V <sub>I(IN)</sub>		2.7	5.5	V
VI	Input voltage, V <sub>I(ENx)</sub> , V <sub>I(/ENx)</sub>	0	5.5	V	
Io	Continuous output current, I <sub>O(OUTx)</sub>		0	1.5	Α
		TPS2060/64	0	105	
$T_{J}$	Operating virtual junction temperature	TPS2068/69 (DGN Package)	-40	105	°C
		0	105		

<sup>(1)</sup> The PowerPad must be connected externally to GND pin to meet qualifying conditions for CB Certificate (DGN package only).

## **ELECTRICAL CHARACTERISTICS**

 $0^{\circ}\text{C} \leq \text{T}_{\text{J}} \leq 105^{\circ}\text{C}$  for the TPS2060/64 and TPS2068 (D package), plus  $-40^{\circ}\text{C} \leq \text{T}_{\text{J}} \leq 105^{\circ}$  for the TPS2068/69 (DGN package),  $V_{\text{I(IN)}} = 5.5 \text{ V}$ ,  $I_{\text{O}} = 1 \text{ A}$ ,  $V_{\text{I(/ENx)}} = 0 \text{ V}$ , or  $V_{\text{I(ENx)}} = 5.5 \text{ V}$  (unless otherwise noted).

	PARAMETER	, ,	NDITIONS(1)		MIN	TYP	MAX	UNIT
POWER S	WITCH							
r <sub>DS(on)</sub>	Static drain-source on-state resistance, 5-V operation and 3.3-V operation	$V_{I(IN)} = 5 \text{ V or } 3.3 \text{ V, } I_O = 1.5 \text{ A}$				70	115	mΩ
26(61.)	Static drain-source on-state resistance, 2.7-V operation	V <sub>I(IN)</sub> = 2.7 V, I <sub>O</sub> = 1.5 A	$V_{I(IN)} = 2.7 \text{ V}, I_O = 1.5 \text{ A}$					
	Di di di	V <sub>I(IN)</sub> = 5.5 V				0.6 1.		
t <sub>r</sub>	Rise time, output	V <sub>I(IN)</sub> = 2.7 V	C <sub>L</sub> = 1 μF,	T 0500		0.4	1	
		$V_{I(IN)} = 5.5 \text{ V}$ $R_L = 5 \Omega$		$T_J = 25^{\circ}C$	0.05		0.5	ms
t <sub>f</sub>	Fall time, output	V <sub>I(IN)</sub> = 2.7 V			0.05		0.5	
ENABLE II	NPUT EN OR EN			1				
V <sub>IH</sub>	High-level input voltage	2.7 V < V <sub>I(IN)</sub> < 5.5 V			2			V
V <sub>IL</sub>	Low-level input voltage	2.7 V < V <sub>I(IN)</sub> < 5.5 V						
I <sub>I</sub>	Input current	$V_{I(/ENx)} = 0 \text{ V or 5.5 V, } V_{I(ENx)} =$	-0.5		0.5	μA		
t <sub>on</sub>	Turnon time	$C_L = 100 \ \mu F, R_L = 5 \ \Omega$			3	<u> </u>		
t <sub>off</sub>	Turnoff time	$C_L = 100  \mu F,  R_L = 5  \Omega$			10	ms		
CURRENT	LIMIT						ı	
I <sub>OS</sub>	Short-circuit output current	V <sub>I(IN)</sub> = 5 V, OUT connected to short-circuit	1.6	2.1	2.6	Α		
		V <sub>I(IN)</sub> = 5 V, Current ramp	- 5 V Current ramp			3.2	3.9	
I <sub>OC_TRIP</sub>	Overcurrent trip threshold	(≤ 100 A/s) on OUT		TPS2068/69	2.3	2.85	3.4	Α
I <sub>OS</sub> (2)	Short-circuit output current	V <sub>I(IN)</sub> = 5 V, OUT1 and OUT2 c into short-circuit, current measu		D, Device enabled	3.2	4.2	5.2	А
I <sub>OC_TRIP</sub> (2)	Overcurrent trip threshold TPS2060/64	V <sub>I(IN)</sub> = 5 V, Current ramp (≤ 10 together, current measured at V		and OUT2 tied		6.4	7.8	Α
		No load on OUT, $V_{I(/ENx)} = 5.5$	/	T <sub>.1</sub> = 25°C		0.5	1	
I <sub>OL</sub>	Supply current, low-level output	or $V_{I(ENx)} = 0 \text{ V}$	•,	Over T <sub>J</sub> range		0.5	5	μA
	Supply current, high-level output	No load on OUT, V <sub>I(/ENx)</sub> = 0 V,		T <sub>.1</sub> = 25°C		50	70	
I <sub>OH</sub>	TPS2060/64	or $V_{I(ENx)} = 5.5 \text{ V}$		Over T <sub>1</sub> range		50	90	μA
	Supply current, high-level output	No load on OUT, V <sub>I(/ENx)</sub> = 0 V,		T <sub>.1</sub> = 25°C		43	60	
I <sub>OH</sub>	TPS2068/69	or $V_{I(ENx)} = 5.5 \text{ V}$		Over T <sub>1</sub> range		43	70	μA
I <sub>lkg</sub>	Leakage current	OUT connected to ground, V <sub>I(/E</sub> or V <sub>I(FNx)</sub> = 0 V		1		μA		
	Reverse leakage current	$V_{I(OUTx)} = 5.5 \text{ V}, IN = ground$		0.2		μA		
UNDERVO	DLTAGE LOCKOUT			1 -	1			
	Low-level input voltage, IN				2		2.5	V
	Hysteresis, IN	T <sub>.1</sub> = 25°C				75		mV

Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

<sup>(2)</sup> This configuration has not been tested for UL certification.



# **ELECTRICAL CHARACTERISTICS (continued)**

 $0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 105^{\circ}\text{C}$  for the TPS2060/64 and TPS2068 (D package), plus  $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 105^{\circ}$  for the TPS2068/69 (DGN package),  $V_{\text{I(IN)}} = 5.5 \text{ V}$ ,  $V_{\text{I(IN)}} = 5.5 \text{ V}$ , or  $V_{\text{I(IN)}} = 5.5 \text{ V}$ , (unless otherwise noted).

	PARAMETER	TEST CONDITIONS <sup>(1)</sup>	MIN	TYP	MAX	UNIT
OVERCUE	RRENT OCx					
V <sub>OL(/OCx)</sub>	Output low voltage	$I_{O(/OCx)} = 5 \text{ mA}$			0.4	V
	Off-state current	$V_{O(/OCx)} = 5 \text{ V or } 3.3 \text{ V}$			1	μA
	OC deglitch	OCx assertion or deassertion	4	8	15	ms
THERMAL	SHUTDOWN <sup>(3)</sup>		·			
	Thermal shutdown threshold		135			°C
	Recovery from thermal shutdown		125			°C
	Hysteresis			10		°C

<sup>(3)</sup> The thermal shutdown only reacts under overcurrent conditions.

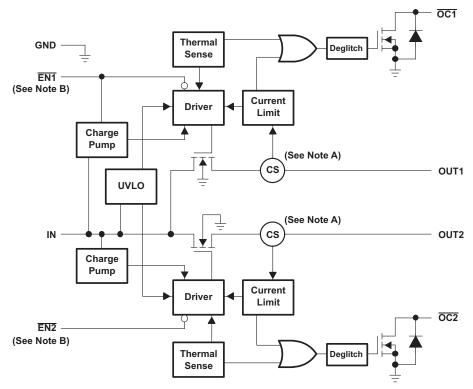
## **DEVICE INFORMATION**

#### **Pin Functions**

	PINS		I/O	DESCRIPTION					
DGN	and DRB PA	CKAGES	2	DESCRIP HON					
NAME	TPS2060	TPS2064							
EN1	3	_	_	Enable input, logic low turns on power switch IN-OUT1					
EN2	4	_	_	Enable input, logic low turns on power switch IN-OUT2					
EN1	_	_ 3 I		Enable input, logic high turns on power switch IN-OUT1					
EN2	_	4	_	Enable input, logic high turns on power switch IN-OUT2					
GND	1	1		Ground					
IN	2	2	_	Input voltage					
OC1	8	8	0	Overcurrent, open-drain output, active low, IN-OUT1					
OC2	5	5	0	Overcurrent, open-drain output, active low, IN-OUT2					
OUT1	7	7	0	Power-switch output, IN-OUT1					
OUT2	OUT2 6 6 0		0	Power-switch output, IN-OUT2					
	PowerPad PowerPad			Connect to GND					



# Functional Block Diagram (TPS2060 and TPS2064)



- A. Current sense.
- B. Active low (ENx) for TPS2060. Active high (ENx) for TPS2064.



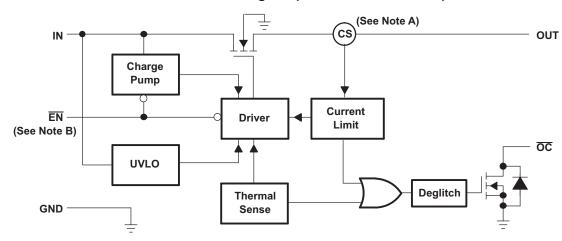
## **DEVICE INFORMATION**

## Pin Functions (TPS2068 and TPS2069)

	PINS		1/0	DESCRIPTION
NAME	TPS2068	TPS2069	1/0	DESCRIPTION
EN	4	_	I	Enable input, logic low turns on power switch
EN	_	4	- 1	Enable input, logic high turns on power switch
GND	1	1		Ground
IN	2, 3	2, 3	1	Input voltage
<del>OC</del>	5	5	0	Overcurrent, open-drain output, active-low
OUT	6, 7, 8	6, 7, 8	0	Power-switch output
	PowerPad	PowerPad		Connect to GND (DGN Package Only) <sup>(1)</sup>

(1) See the Recommended Operating Conditions Table for PowerPad connection guidelines to meet qualifying conditions for CB Certificate (DGN package only).

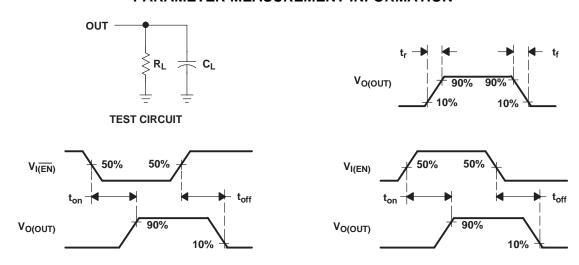
# Functional Block Diagram (TPS2068 and TPS2069)



- Current sense.
- B. Active low (EN) for TPS2068. Active high (EN) for TPS2069.



## PARAMETER MEASUREMENT INFORMATION



**VOLTAGE WAVEFORMS** 

Figure 1. Test Circuit and Voltage Waveforms

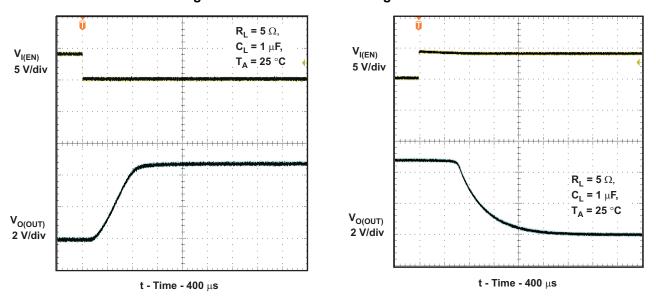


Figure 2. Turnon Delay and Rise Time With 1- $\mu$ F Load

Figure 3. Turnoff Delay and Fall Time With 1- $\mu$ F Load

# TEXAS INSTRUMENTS

# PARAMETER MEASUREMENT INFORMATION (continued)

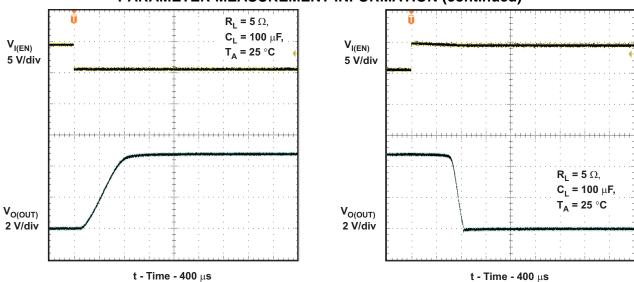


Figure 4. Turnon Delay and Rise Time With 100-μF Load

Load

V<sub>IN</sub> = 5 V,
R<sub>L</sub> = 3 Ω,
T<sub>A</sub> = 25°C

220 μF

470 μF

500 mA/div

Figure 5. Turnoff Delay and Fall Time With 100-µF

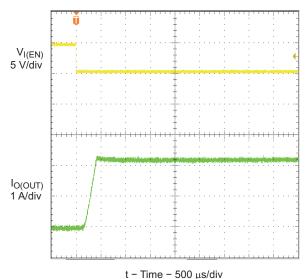


Figure 6. Short-Circuit Current, Device Enabled Into Short

Figure 7. Inrush Current With Different Load Capacitance

t - Time - 500 μs/div

8



# PARAMETER MEASUREMENT INFORMATION (continued)

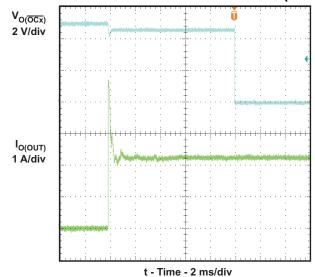
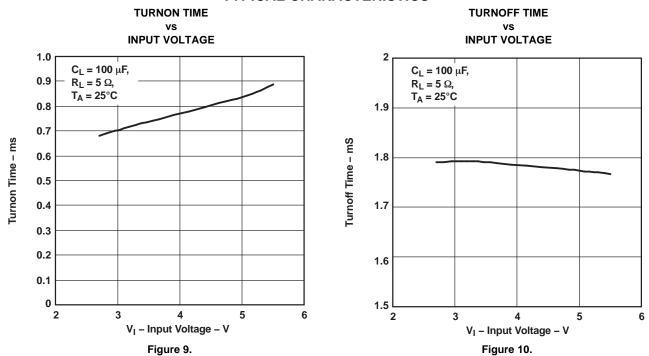
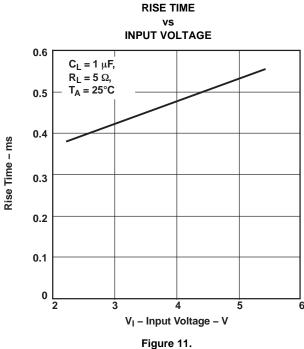


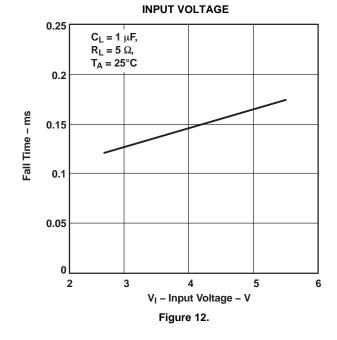
Figure 8. 0.6-Ω Load Connected to Enabled Device

# **TYPICAL CHARACTERISTICS**



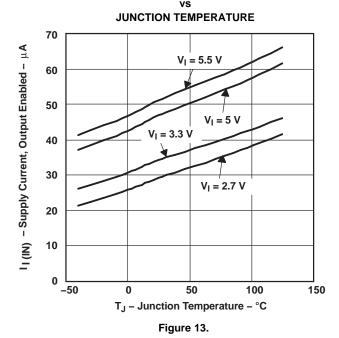
# **TYPICAL CHARACTERISTICS (continued)**





**FALL TIME** 

TPS2060, TPS2064 SUPPLY CURRENT, OUTPUT ENABLED



TPS2068, TPS2069 SUPPLY CURRENT, OUTPUT ENABLED

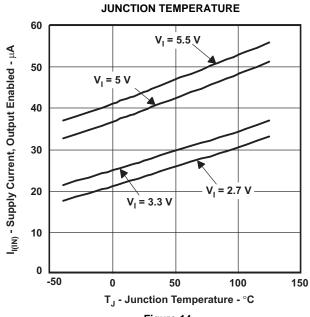


Figure 14.



# **TYPICAL CHARACTERISTICS (continued)**

## SUPPLY CURRENT, OUTPUT DISABLED

## JUNCTION TEMPERATURE 0.5 I (IN) – Supply Current, Output Disabled – $\,\mu\text{A}$ $V_1 = 5.5 \text{ V}$ $V_I = 5 V$ 0.4 0.35 = 3.3 V0.3 $V_1 = 2.7 \text{ V}$ 0.25 0.2 0.15 0.1 0.05 0 -50 50 150 T<sub>J</sub> - Junction Temperature - °C

Figure 15.

# STATIC DRAIN-SOURCE ON-STATE RESISTANCE

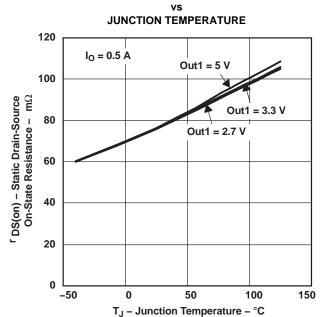
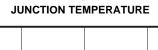


Figure 16.

# SHORT-CIRCUIT OUTPUT CURRENT



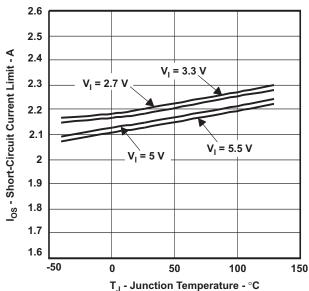


Figure 17.

# **UNDERVOLTAGE LOCKOUT** JUNCTION TEMPERATURE

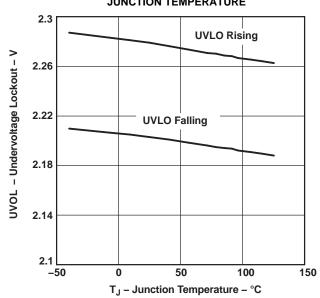
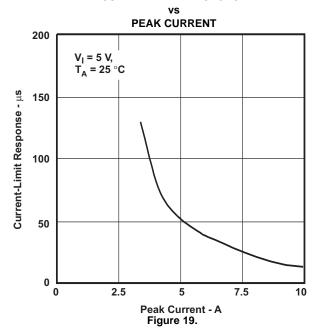


Figure 18.



# **TYPICAL CHARACTERISTICS (continued)**

CURRENT-LIMIT RESPONSE





#### APPLICATION INFORMATION

#### **POWER-SUPPLY CONSIDERATIONS**

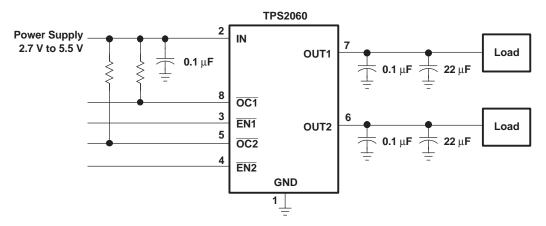


Figure 20. Typical Application

A 0.01-µF to 0.1-µF ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01-µF to 0.1-µF ceramic capacitor improves the immunity of the device to short-circuit transients.

#### **OVERCURRENT**

A sense FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before  $V_{I(IN)}$  has been applied (see Figure 6). The TPS206x senses the short and immediately switches into a constant-current output.

In the second condition, a short or an overload occurs while the device is enabled. At the instant the overload occurs, high currents may flow for a short period of time before the current-limit circuit can react (see Figure 8). After the current-limit circuit has tripped (reached the overcurrent trip threshold), the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded. The TPS206x is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

## **OC RESPONSE**

The OCx open-drain output is asserted (active low) when an overcurrent or overtemperature shutdown condition is encountered after a 10-ms deglitch timeout. The output remains asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause a momentary overcurrent condition; however, no false reporting on  $\overline{OCx}$  occurs due to the 10-ms deglitch circuit. The TPS206x is designed to eliminate false overcurrent reporting. The internal overcurrent deglitch eliminates the need for external components to remove unwanted pulses.  $\overline{OCx}$  is not deglitched when the switch is turned off due to an overtemperature shutdown.

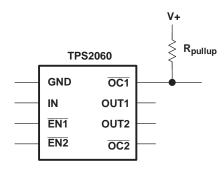


Figure 21. Typical Circuit for the OC Pin

## POWER DISSIPATION AND JUNCTION TEMPERATURE

The low on-resistance on the N-channel MOSFET allows the small surface-mount packages to pass large currents. The thermal resistance of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. Begin by determining the  $r_{DS(on)}$  of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{DS(on)}$  from Figure 16. Using this value, the power dissipation per switch can be calculated by:

$$P_D = r_{DS(on)} \times I^2$$

Multiply this number by the number of switches being used. This step renders the total power dissipation from the N-channel MOSFETs.

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

T<sub>A</sub>= Ambient temperature °C

 $R_{\theta JA}$  = Thermal resistance

P<sub>D</sub> = Total power dissipation based on number of switches being used.

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

## THERMAL PROTECTION

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The TPS206x implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. In an overcurrent or short-circuit condition, the junction temperature rises due to excessive power dissipation. Once the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 10°C, the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The  $\overline{OCx}$  open-drain output is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

## UNDERVOLTAGE LOCKOUT (UVLO)

An undervoltage lockout ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO also keeps the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. On reinsertion, the power switch is turned on, with a controlled rise time to reduce EMI and voltage overshoots.



## **UNIVERSAL SERIAL BUS (USB) APPLICATIONS**

The universal serial bus (USB) interface is a 12-Mb/s, or 1.5-Mb/s, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (e.g., keyboards, printers, scanners, and mice). The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply.

The USB specification defines the following five classes of devices, each differentiated by power-consumption requirements:

- Hosts/self-powered hubs (SPH)
- Bus-powered hubs (BPH)
- Low-power, bus-powered functions
- High-power, bus-powered functions
- · Self-powered functions

SPHs and BPHs distribute data and power to downstream functions. The TPS206x has higher current capability than required by one USB port; so, it can be used on the host side and supplies power to multiple downstream ports or functions.

#### HOST/SELF-POWERED AND BUS-POWERED HUBS

Hosts and SPHs have a local power supply that powers the embedded functions and the downstream ports (see Figure 22). This power supply must provide from 5.25 V to 4.75 V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current-limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.



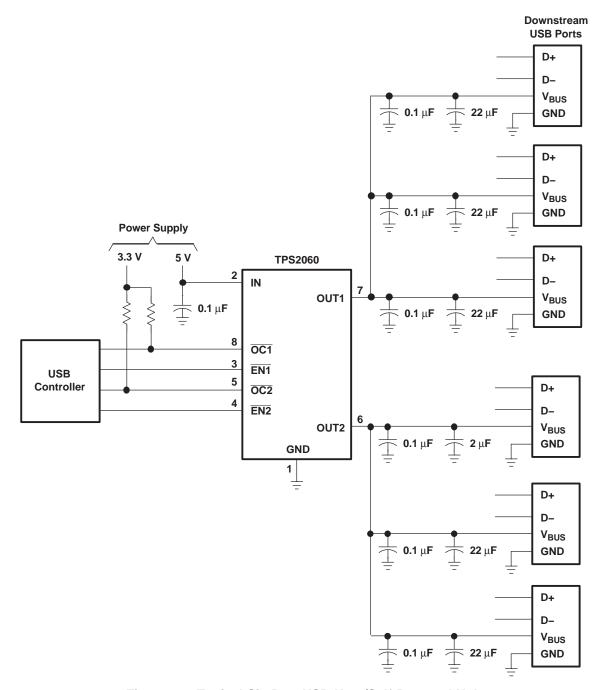


Figure 22. Typical Six-Port USB Host/Self-Powered Hub

BPHs obtain all power from upstream ports and often contain an embedded function. The hubs are required to power up with less than one unit load. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on power up, the power to the embedded function may need to be kept off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than one unit load. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.



#### LOW-POWER BUS-POWERED AND HIGH-POWER BUS-POWERED FUNCTIONS

Both low-power and high-power bus-powered functions obtain all power from upstream ports; low-power functions always draw less than 100 mA; high-power functions must draw less than 100 mA at power up and can draw up to 500 mA after enumeration. If the load of the function is more than the parallel combination of 44  $\Omega$  and 10  $\mu$ F at power up, the device must implement inrush current limiting (see Figure 23). With TPS206x, the internal functions could draw more than 500 mA, which fits the needs of some applications such as motor driving circuits.

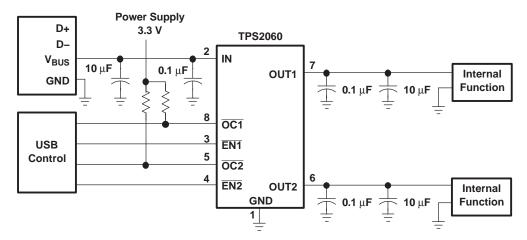


Figure 23. High-Power Bus-Powered Function

#### **USB POWER-DISTRIBUTION REQUIREMENTS**

USB can be implemented in several ways, and, regardless of the type of USB device being developed, several power-distribution features must be implemented.

- · Hosts/SPHs must:
  - Current-limit downstream ports
  - Report overcurrent conditions on USB V<sub>BUS</sub>
- BPHs must:
  - Enable/disable power to downstream ports
  - Power up at <100 mA</li>
  - Limit inrush current (<44 Ω and 10 μF)</li>
- · Functions must:
  - Limit inrush currents
  - Power up at <100 mA</li>

The feature set of the TPS206x allows them to meet each of these requirements. The integrated current-limiting and overcurrent reporting is required by hosts and self-powered hubs. The logic-level enable and controlled rise times meet the need of both input and output ports on bus-powered hubs, as well as the input ports for bus-powered functions (see Figure 24).



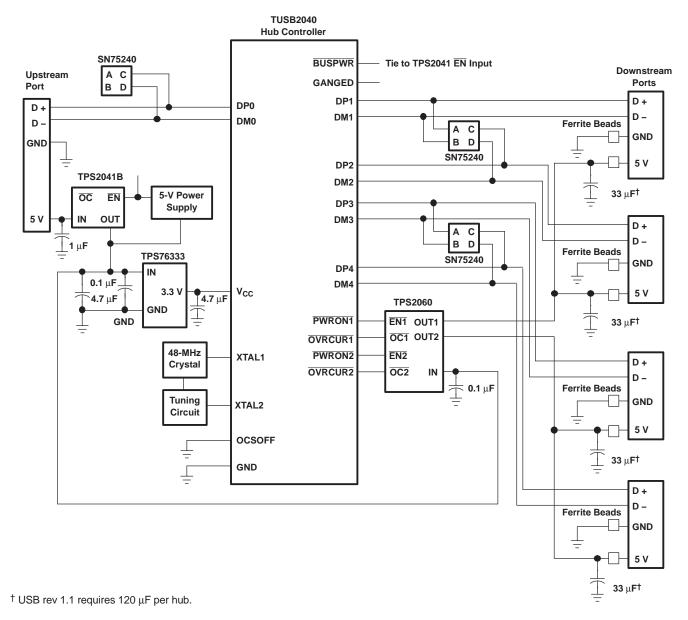


Figure 24. Hybrid Self / Bus-Powered Hub Implementation

## **GENERIC HOT-PLUG APPLICATIONS**

In many applications it may be necessary to remove modules or pc boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the TPS206x, these devices can be used to provide a softer start-up to devices being hot-plugged into a powered system. The UVLO feature of the TPS206x also ensures that the switch is off after the card has been removed, and that the switch is off during the next insertion. The UVLO feature insures a soft start with a controlled rise time for every insertion of the card or module.



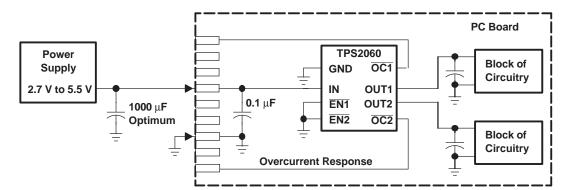


Figure 25. Typical Hot-Plug Implementation

By placing the TPS206x between the  $V_{CC}$  input and the rest of the circuitry, the input power reaches these devices first after insertion. The typical rise time of the switch is approximately 1 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.

#### **DETAILED DESCRIPTION**

#### **Power Switch**

The power switch is an N-channel MOSFET with a low on-state resistance. Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum current of 1.5 A.

## **Charge Pump**

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires little supply current.

#### **Driver**

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage.

## Enable (ENx)

The logic enable disables the power switch and the bias for the charge pump, driver, and other circ<u>uitry</u> to reduce the supply current. The supply current is reduced to less than 1 µA when a logic high is present on ENx, or when a logic low is present on ENx. A logic zero input on ENx, or a logic high input on ENx restores bias to the drive and control circuits and turns the switch on. The enable input is compatible with both TTL and CMOS logic levels.

# Overcurrent (OCx)

The  $\overline{OCx}$  open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output remains <u>asserted</u> until the overcurrent or overtemperature condition is removed. A 10-ms deglitch circuit prevents the  $\overline{OCx}$  signal from oscillation or false triggering. If an overtemperature shutdown occurs, the  $\overline{OCx}$  is asserted instantaneously.



#### **Current Sense**

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant-current mode and holds the current constant while varying the voltage on the load.

#### **Thermal Sense**

The TPS206x implements a thermal sensing to monitor the operating temperature of the power distribution switch. In an overcurrent or short-circuit condition the junction temperature rises. When the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns off the switch, thus preventing the device from damage. Hysteresis is built into the thermal sense, and after the device has cooled approximately 10 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed. The open-drain false reporting output  $(\overline{OCx})$  is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

#### **Undervoltage Lockout**

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2 V, a control signal turns off the power switch.





6-Feb-2020

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2060DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	0 to 70	2060	Samples
TPS2060DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	0 to 70	2060	Samples
TPS2060DRBR	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2060	Samples
TPS2060DRBT	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2060	Samples
TPS2064DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	0 to 70	2064	Samples
TPS2064DGNG4	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-1-260C-UNLIM	0 to 70	2064	Samples
TPS2064DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	0 to 70	2064	Samples
TPS2064DRBR	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2064	Samples
TPS2064DRBT	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2064	Samples
TPS2068D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	0 to 70	2068	Samples
TPS2068DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2068	Samples
TPS2068DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2068	Samples
TPS2068DGNRG4	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2068	Samples
TPS2068DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	0 to 70	2068	Samples
TPS2069DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2069	Samples
TPS2069DGNG4	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2069	Samples
TPS2069DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2069	Samples



# PACKAGE OPTION ADDENDUM

6-Feb-2020

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS2069DGNRG4	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2069	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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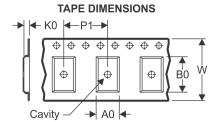
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# PACKAGE MATERIALS INFORMATION

www.ti.com 6-Sep-2019

# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



## \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2060DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2060DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2060DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2064DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2064DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2064DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2064DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS2068DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2068DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2068DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2069DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2069DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

www.ti.com 6-Sep-2019



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2060DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2060DRBR	SON	DRB	8	3000	346.0	346.0	35.0
TPS2060DRBT	SON	DRB	8	250	203.0	203.0	35.0
TPS2064DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2064DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
TPS2064DRBR	SON	DRB	8	3000	346.0	346.0	35.0
TPS2064DRBT	SON	DRB	8	250	203.0	203.0	35.0
TPS2068DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
TPS2068DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2068DR	SOIC	D	8	2500	533.4	186.0	36.0
TPS2069DGNR	HVSSOP	DGN	8	2500	346.0	346.0	35.0
TPS2069DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203482/L





PLASTIC SMALL OUTLINE - NO LEAD



#### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE INTEGRATED CIRCUIT



## NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGN (S-PDSO-G8)

# PowerPAD™ PLASTIC SMALL OUTLINE



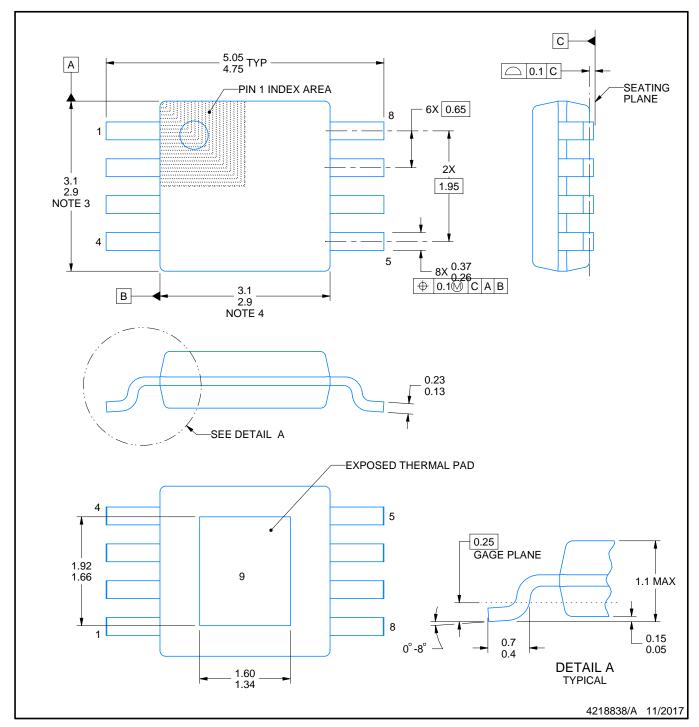
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="https://www.ti.com">www.ti.com</a>.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-187 variation AA-T

#### PowerPAD is a trademark of Texas Instruments.







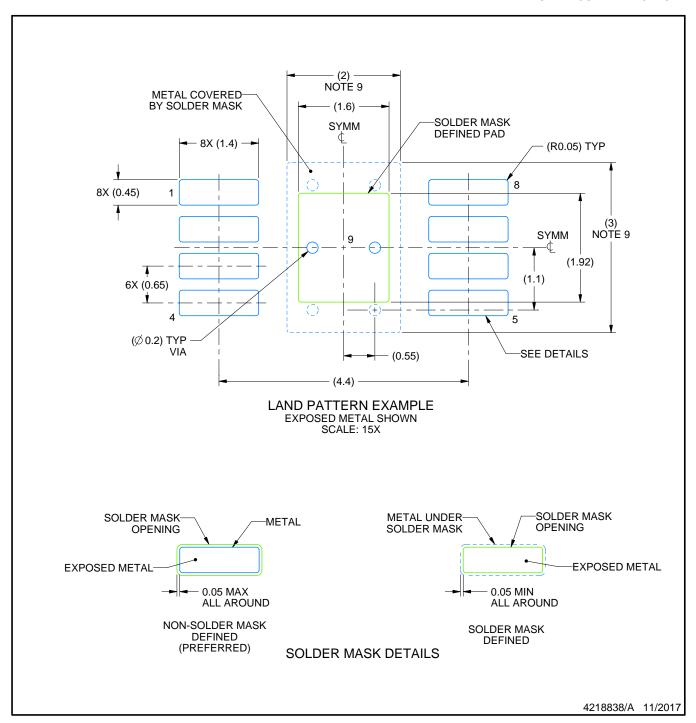
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.

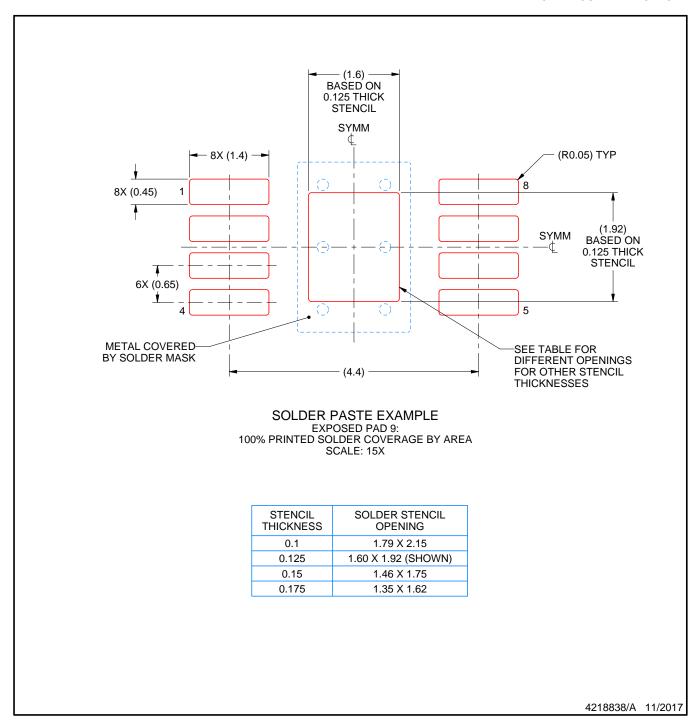




NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.





NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



# $\textbf{PowerPAD}^{^{\text{\tiny{TM}}}}\,\textbf{VSSOP - 1.1 mm max height}$

SMALL OUTLINE PACKAGE



#### NOTES:

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- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.





NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.





NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



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